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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of Response Under 37 CFR 1.116 - Expedited Procedure

: Customer Number: 20277

Masatoshi TAYA

: Confirmation Number: 3872

Application No.: 10/611,857

: Group Art Unit: 2822

Filed: July 03, 2003

: Examiner: Ida M. Soward

For: SEMICONDUCTOR DEVICE INCLUDING A HIGH-BREAKDOWN VOLTAGE MOS TRANSISTOR

Mail Stop AF

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Dear Sir:

Transmitted herewith is an Amendment in the above-identified application.

☐ No additional fee is required.☐ Applicant is entitled to small entity status under 37 CFR 1.27☐ Also attached:

The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	10	20	0	\$50.00 =	\$0.00
Independent Claims	4	3	1	\$200.00 =	\$200.00
Multiple dependent claims newly presented					\$0.00
Fee for extension of time					\$0.00
					\$0.00
Total of Above Calculations					\$200.00

☒ Please charge my Deposit Account No. 500417 in the amount of \$200.00. An additional copy of this transmittal sheet is submitted herewith.

☒ The Commissioner is hereby authorized to charge payment of any fees associated with this communication or credit any overpayment, to Deposit Account No. 500417, including any filing fees under 37 CFR 1.16 for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

McDERMOTT WILL & EMERY LLP

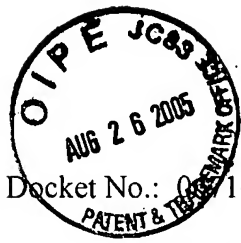


Gene Z. Robinson

Registration No. 33,351

600 13th Street, N.W.
Washington, DC 20005-3096
Phone: 202.756.8000 GZR:lnm
Facsimile: 202.756.8087
Date: August 26, 2005

Please recognize our Customer No. 20277 as our
correspondence address.



Docket No.: 0161-0045

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Masatoshi TAYA

RESPONSE UNDER 37 CFR 1.116
EXPEDITED PROCEDURE

Application No.: 10/611,857

Customer No.: 20277
Confirmation No.: 3872

Filed: July 03, 2003

Group Art Unit: 2822

Examiner: Ida M. Soward

Title: SEMICONDUCTOR DEVICE INCLUDING A HIGH-BREAKDOWN VOLTAGE
MOS TRANSISTOR

AMENDMENT UNDER 37 CFR 1.116

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

The following amendment and remarks are submitted in response to the final Office

Action dated June 3, 2005.

Amendments to the Claims are reflected in the listing of claims which begins on page 2
of this paper. This listing of claims replaces all prior versions, and listings, of claims in the
application.

Remarks begin on page 9 of this paper.

08/29/2005 SZEWDIE1 00000052 500417 10611857

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